#### **Features**

- 512K x 8 advanced high-speed CMOS Static RAM
- JEDEC Center Power / GND pinout for reduced noise
- Equal access and cycle times
   Commercial and Industrial: 10/12/15ns
- Single 3.3V power supply
- One Chip Select plus one Output Enable pin
- Bidirectional data inputs and outputs directly TTL-compatible
- Low power consumption via chip deselect
- Available in 36-pin, 400 mil plastic SOJ package and 44-pin, 400 mil TSOP.
- Industrial temperature range (-40°C to +85°C) is available for selected speeds

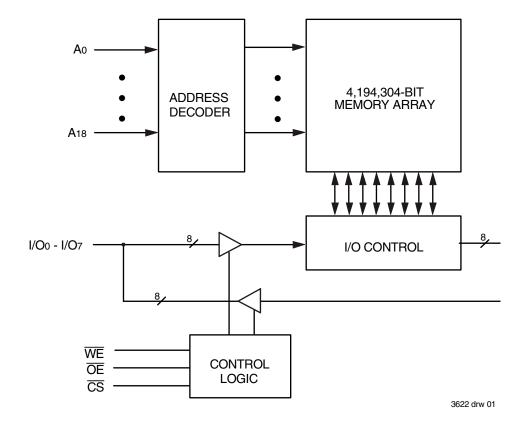
### Description

The IDT71V424 is a 4,194,304-bit high-speed Static RAM organized as  $512K \times 8$ . It is fabricated using high-performance, high-reliability CMOS technology. This state-of-the-art technology, combined with innovative circuit design techniques, provides a cost-effective solution for high-speed memory needs.

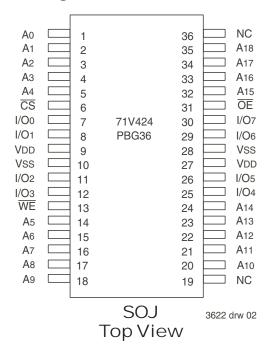
The IDT71V424 has an output enable pin which operates as fast as 5ns, with address access times as fast as 10ns. All bidirectional inputs and outputs of the IDT71V424 are TTL-compatible and operation is from a single 3.3V supply. Fully static asynchronous circuitry is used, requiring no clocks or refresh for operation.

The IDT71V424 is packaged in a 36-pin, 400 mil Plastic SOJ and 44-pin, 400 mil TSOP.

## Functional Block Diagram

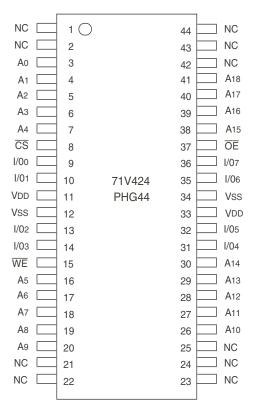


# Pin Configurations<sup>(1)</sup>



#### NOTE:

1. This text does not indicate orientation of actual part-marking.



TSOP 36 Top View

3622 drw 11

## Pin Description

A0 – A18	Address Inputs	Input
<del>CS</del>	Chip Select	Input
WE	Write Enable	Input
ŌĒ	Output Enable	Input
I/O <sub>0</sub> - I/O <sub>7</sub>	Data Input/Output	I/O
VDD	3.3V Power	Power
Vss	Ground	Gnd

3622 tbl 02

## Capacitance

 $(TA = +25^{\circ}C, f = 1.0MHz, SOJ package)$ 

Symbol	Parameter <sup>(1)</sup>	Conditions	Max.	Unit
Cin	Input Capacitance	VIN = 3dV	7	pF
Cvo	I/O Capacitance	Vout = 3dV	8	pF

2422 +Ы 0.2

#### NOTE:

 This parameter is guaranteed by device characterization, but not production tested.

#### Truth Table<sup>(1,2)</sup>

<del>cs</del>	ŌĒ	WE	l/O	Function
L	L	Н	DATAout	Read Data
L	Х	L	DATAIN	Write Data
L	Н	Н	High-Z	Output Disabled
Н	Χ	Х	High-Z	Deselected - Standby (ISB)
<b>V</b> HC <sup>(3)</sup>	Х	Х	High-Z	Deselected - Standby (ISB1)

3622 tbl 01

- NOTES: 1.  $H = V_{IH}, L = V_{IL}, x = Don't care.$
- 2.  $V_{LC} = 0.2V$ ,  $V_{HC} = V_{DD} 0.2V$ .
- 3. Other inputs  $\geq V_{HC}$  or  $\leq V_{LC}$ .

### Absolute Maximum Ratings<sup>(1)</sup>

Symbol	Rating	Value	Unit
VDD	Supply Voltage Relative to Vss	-0.5 to +4.6	V
VIN, VOUT	Terminal Voltage Relative to Vss	-0.5 to VDD+0.5	V
TBIAS	Temperature Under Bias	-55 to +125	۰C
Тѕтс	Storage Temperature	-55 to +125	°C
Рт	Power Dissipation	1	W
Гоит	DC Output Current	50	mA

#### 3622 tbl 04 NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### Recommended Operating Temperature and Supply Voltage

Grade	Temperature	Vss	<b>V</b> DD
Commercial	0°C to +70°C	0V	See Below
Industrial	-40°C to +85°C	0V	See Below

3622 tbl 05

### Recommended DC Operating Conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
VDD	Supply Voltage	3.0	3.3	3.6	V
Vss	Ground	0	0	0	V
ViH	Input High Voltage	2.0	_	VDD+0.3 <sup>(1)</sup>	V
VIL	Input Low Voltage	-0.3 <sup>(2)</sup>		0.8	V

3622 tbl 06

#### NOTES:

- 1. ViH (max.) = VDD+2V for pulse width less than 5ns, once per cycle.
- 2.  $V_{IL}$  (min.) = -2V for pulse width less than 5ns, once per cycle.

### DC Electrical Characteristics

(VDD = Min. to Max., Commercial and Industrial Temperature Ranges)

			IDT71V424		
Symbol	Parameter	Test Condition	Min.	Max. Unit	
Iu	Input Leakage Current	VDD = Max., VIN = Vss to VDD		5	μA
ILO	Output Leakage Current	VDD = Max., $\overline{\text{CS}}$ = VIH, VOUT = VSS to VDD		5	μA
Vol	Output Low Voltage	IOL = 8mA, VDD = Min.		0.4	V
Vон	Output High Voltage	Iон = -4mA, V <sub>DD</sub> = Min.	2.4		V

3622 tbl 07

## DC Electrical Characteristics(1, 2, 3)

(VDD = Min. to Max., VLC = 0.2V, VHC = VDD - 0.2V)

			71V424S/L 10		71V424S/L 12		71V424S/L 15		Unit
Symbol	Parameter		Com'l.	Ind.	Com'l.	Ind.	Com'l.	Ind.	Unit
loo	$\label{eq:continuous} \begin{array}{ll} \text{Icc} & \frac{\text{Dynamic Operating Current}}{\overline{\text{CS}}} \leq \text{VLc, Outputs Open, VDD} = \text{Max., f} = \text{fmax}^{(4)} \end{array}$	S	180	180	170	170	160	160	mA
ICC		L	165	165	155	155	145	145	mA
ISB	Dynamic Standby Power Supply Current	S	60	60	55	55	50	50	mA
ISB	$\overline{\text{CS}} \ge \text{VHC}$ , Outputs Open, $\text{VDD} = \text{Max.}$ , $f = \text{fmAX}^{(4)}$	L	55	55	50	50	45	45	mA
ISB1	Full Standby Power Supply Current (static)	S	20	20	20	20	20	20	mA
ISBI	$\overline{\text{CS}} \ge \text{VHC}$ , Outputs Open, $\text{VDD} = \text{Max.}$ , $f = 0^{(4)}$	L	10	10	10	10	10	10	mA

#### NOTES:

3622 tbl 08

- 1. All values are maximum guaranteed values.
- 2. All inputs switch between 0.2V (Low) and VDD 0.2V (High).
- 3. Power specifications are preliminary.
- 4. fmax = 1/trc (all address inputs are cycling at fmax); f = 0 means no address input lines are changing.

## **AC Test Conditions**

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	1.5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figure 1, 2 and 3

3622 tbl 09

## **AC Test Loads**

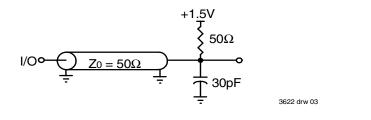
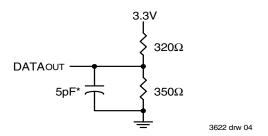


Figure 1. AC Test Load



\*Including jig and scope capacitance.

Figure 2. AC Test Load (for tclz, tolz, tchz, tohz, tow, and twhz)

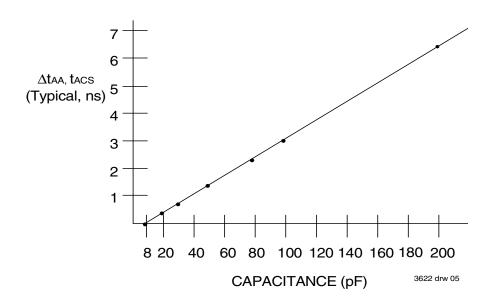


Figure 3. Output Capacitive Derating

## **AC Electrical Characteristics**

(Vcc =  $3.3V \pm 10\%$ , Commercial and Industrial Temperature Ranges)

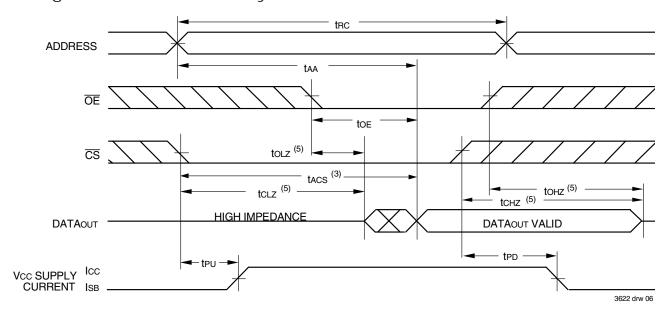
		71V42	4S/L10	71V42	4S/L12	71V42	4S/L15	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
READ CYCLE								
trc	Read Cycle Time	10	_	12	_	15		ns
taa	Address Access Time	_	10		12		15	ns
tacs	Chip Select Access Time		10		12		15	ns
tclz <sup>(1)</sup>	Chip Select to Output in Low-Z	4	_	4	_	4		ns
tcHz <sup>(1)</sup>	Chip Deselect to Output in High-Z	_	5		6		7	ns
toe	Output Enable to Output Valid	_	5		6		7	ns
tolz <sup>(1)</sup>	Output Enable to Output in Low-Z	0	_	0	_	0		ns
tonz <sup>(1)</sup>	Output Disable to Output in High-Z	_	5		6		7	ns
tон	Output Hold from Address Change	4		4		4		ns
tpu <sup>(1)</sup>	Chip Select to Power Up Time	0	_	0		0		ns
tpD <sup>(1)</sup>	Chip Deselect to Power Down Time	_	10		12		15	ns
WRITE CYCL	E							
twc	Write Cycle Time	10		12		15		ns
taw	Address Valid to End of Write	8	_	8	_	10		ns
tcw	Chip Select to End of Write	8	_	8	_	10		ns
tas	Address Set-up Time	0		0	_	0		ns
twp	Write Pulse Width	8	_	8	_	10		ns
twr	Write Recovery Time	0		0		0		ns
tow	Data Valid to End of Write	6	_	6	_	7		ns
tон	Data Hold Time	0		0		0		ns
tow <sup>(1)</sup>	Output Active from End of Write	3	—	3		3		ns
twnz <sup>(1)</sup>	Write Enable to Output in High-Z	_	6		7		7	ns

3622 tbl 10

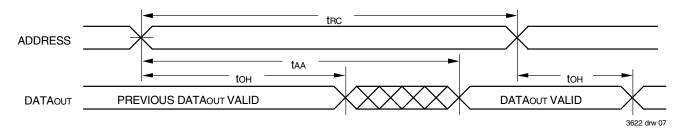
#### NOTE:

1. This parameter guaranteed with the AC load (Figure 2) by device characterization, but is not production tested.

# Timing Waveform of Read Cycle No. 1(1)



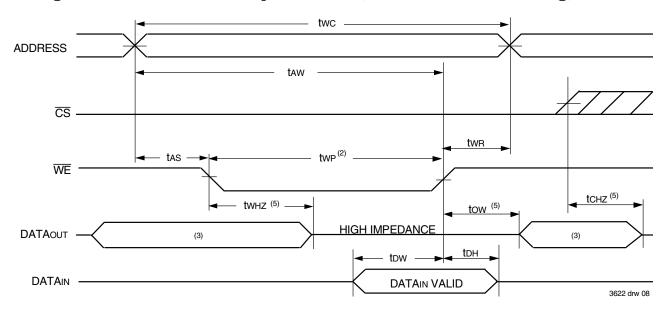
# Timing Waveform of Read Cycle No. 2<sup>(1, 2, 4)</sup>



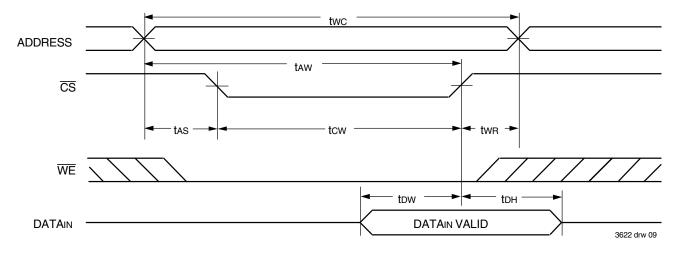
#### NOTES:

- 1.  $\overline{\text{WE}}$  is HIGH for Read Cycle.
- 2. Device is continuously selected,  $\overline{\text{CS}}$  is LOW.
- 3. Address must be valid prior to or coincident with the later of  $\overline{CS}$  transition LOW; otherwise tax is the limiting parameter.
- 4.  $\overline{OE}$  is LOW.
- 5. Transition is measured ±200mV from steady state.

# Timing Waveform of Write Cycle No. 1 (WE Controlled Timing)(1, 2, 4)



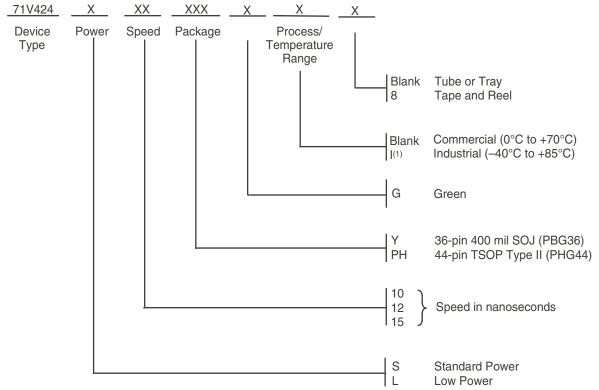
# Timing Waveform of Write Cycle No. 2 (CS Controlled Timing)(1, 4)



#### NOTES:

- 1. A write occurs during the overlap of a LOW  $\overline{\text{CS}}$  and a LOW  $\overline{\text{WE}}$ .
- 2.  $\overline{\text{OE}}$  is continuously  $\overline{\text{HIGH}}$ . During a  $\overline{\text{WE}}$  controlled write cycle with  $\overline{\text{OE}}$  LOW, two must be greater than or equal to twHz + tow to allow the I/O drivers to turn off and data to be placed on the bus for the required tow. If  $\overline{\text{OE}}$  is HIGH during a  $\overline{\text{WE}}$  controlled write cycle, this requirement does not apply and the minimum write pulse is the specified twp.
- 3. During this period, I/O pins are in the output state, and input signals must not be applied.
- 4. If the CS LOW transition occurs simultaneously with or after the WE LOW transition, the outputs remain in a high impedance state. CS must be active during the tcw write period.
- 5. Transition is measured ±200mV from steady state.

## **Ordering Information**



NOTE:

1. Contact your local sales office for industrial temp. range for other speeds, packages and powers.

3622 drw 10

# Orderable Part Information

Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
71V424L10PHG	PHG44	TSOP	С
71V424L10PHG8	PHG44	TSOP	С
71V424L10PHGI	PHG44	TSOP	1
71V424L10PHGl8	PHG44	TSOP	1
71V424L10YG	PBG36	SOJ	С
71V424L10YG8	PBG36	SOJ	С
71V424L10YGI	PBG36	SOJ	- 1
71V424L10YGl8	PBG36	SOJ	- 1
71V424L12PHG	PHG44	TSOP	С
71V424L12PHG8	PHG44	TSOP	С
71V424L12PHGI	PHG44	TSOP	- 1
71V424L12PHGl8	PHG44	TSOP	- 1
71V424L12YG	PBG36	SOJ	С
71V424L12YG8	PBG36	SOJ	С
71V424L12YGI	PBG36	SOJ	- 1
71V424L12YGI8	PBG36	SOJ	- 1
71V424L15PHG	PHG44	TSOP	С
71V424L15PHG8	PHG44	TSOP	С
71V424L15PHGI	PHG44	TSOP	1
71V424L15PHGI8	PHG44	TSOP	I
71V424L15YG	PBG36	SOJ	С
71V424L15YG8	PBG36	SOJ	С
71V424L15YGI	PBG36	SOJ	- 1
	Orderable Part ID  71V424L10PHG 71V424L10PHG8 71V424L10PHGI 71V424L10PHGI8 71V424L10YG 71V424L10YG 71V424L10YGI 71V424L10YGI 71V424L12PHG 71V424L12PHGI 71V424L12PHGI 71V424L12PHGI8 71V424L12YG 71V424L12YG 71V424L12YG 71V424L12YGI 71V424L12YGI 71V424L12YGI 71V424L15PHG 71V424L15PHG 71V424L15PHG 71V424L15PHG 71V424L15PHGI 71V424L15PHGI 71V424L15PHGI 71V424L15PHGI	71V424L10PHG PHG44 71V424L10PHG8 PHG44 71V424L10PHGI PHG44 71V424L10PHGI PHG44 71V424L10PHGI PHG44 71V424L10YG PBG36 71V424L10YG PBG36 71V424L10YGI PBG36 71V424L10YGI PBG36 71V424L10YGI PBG36 71V424L12PHG PHG44 71V424L12PHG PHG44 71V424L12PHGI PHG44 71V424L12PHGI PHG44 71V424L12YG PBG36 71V424L12YG PBG36 71V424L12YG PBG36 71V424L12YGI PBG36 71V424L12YGI PBG36 71V424L12YGI PBG36 71V424L12YGI PBG36 71V424L15PHG PHG44 71V424L15PHG PHG44 71V424L15PHG PHG44 71V424L15PHGI PHG44	Orderable Part ID         Pkg. Code         Pkg. Type           71V424L10PHG         PHG44         TSOP           71V424L10PHG8         PHG44         TSOP           71V424L10PHGI         PHG44         TSOP           71V424L10PHGI8         PHG44         TSOP           71V424L10PHGI8         PHG44         TSOP           71V424L10YG         PBG36         SOJ           71V424L10YGI         PBG36         SOJ           71V424L10YGI8         PBG36         SOJ           71V424L12PHG         PHG44         TSOP           71V424L12PHG8         PHG44         TSOP           71V424L12PHGI8         PHG44         TSOP           71V424L12PHGI8         PHG44         TSOP           71V424L12YG         PBG36         SOJ           71V424L12YGI         PBG36         SOJ           71V424L12YGI         PBG36         SOJ           71V424L12YGI8         PBG36         SOJ           71V424L15PHG         PHG44         TSOP           71V424L15PHGI         PHG44         TSOP           71V424L15PHGI         PHG44         TSOP           71V424L15PHGI         PHG44         TSOP           71V424L15PHGI8

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V424S10PHG	PHG44	TSOP	С
	71V424S10PHG8	PHG44	TSOP	С
	71V424S10PHGI	PHG44	TSOP	I
	71V424S10PHGI8	PHG44	TSOP	- 1
	71V424S10YG	PBG36	SOJ	С
	71V424S10YG8	PBG36	SOJ	С
	71V424S10YGI	PBG36	SOJ	- 1
	71V424S10YGl8	PBG36	SOJ	I
12	71V424S12PHG	PHG44	TSOP	С
	71V424S12PHG8	PHG44	TSOP	С
	71V424S12PHGI	PHG44	TSOP	1
	71V424S12PHGl8	PHG44	TSOP	I
	71V424S12YG	PBG36	SOJ	С
	71V424S12YG8	PBG36	SOJ	С
	71V424S12YGI	PBG36	SOJ	I
	71V424S12YGl8	PBG36	SOJ	I
15	71V424S15PHG	PHG44	TSOP	С
	71V424S15PHG8	PHG44	TSOP	С
	71V424S15PHGI	PHG44	TSOP	I
	71V424S15PHGl8	PHG44	TSOP	I
	71V424S15YG	PBG36	SOJ	С
	71V424S15YG8	PBG36	SOJ	С
	71V424S15YGI	PBG36	SOJ	I
	71V424S15YGl8	PBG36	SOJ	I

# Datasheet Document History

8/13/99		Updated to new format
	Pg. 2	Removed SO44-1 from TSOP pinout
	Pg. 7	Revised footnotes on Write Cycle No. 1 diagram
	· ·	Removed footnote for twn on Write Cycle No. 2 diagram
	Pg. 9	Added Datasheet Document History
8/31/99	Pg. 1–9	Added Industrial temperature range offerings
11/22/02	Pg. 8	Added die revision option to ordering information
07/31/03	Pg. 8	Updated note, L10 speed grade commercial temperature only and updated die stepping from YF to Y.
07/28/04	Pg. 3	Increased ISB for all "L" and S15 speeds by 10mA and increased for S12 speed by 5mA (refer to
	· ·	PCN# SR-0402-02).
	Pg. 8	Added "Restricted hazardous substance device" to the ordering information.
09/20/08	Pg. 1, 8	Added Y and V step part numbers to front page and ordering information. Updated the ordering
		information by removing the "IDT" notation.
05/12/09	Pg. 3,5,8	Add Industrial grade for 10ns Low Power.
06/11/09	Pg.1,8	Removed VS, VL from datasheet and ordering information.
09/26/13:	Pg.1-9	Removed the /YS & /YL from the device name for the entire datasheet.
	Pg.1	Removed IDT's reference to fabrication.
	Pg.8	Updated ordering information by adding T&R, updated Restricted Hazardous Substance Device
		wording to Green and removed the Die Stepping Revision, the "Y" designator.
05/04/21	Pg.1-11	Rebranded as Renesas datasheet
	Pg.2 & 8	Updated package codes
	Pg.8	Added Industrial temp footnote to Ordering Information
	Pg.9	Added Orderable Part Information tables

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(Rev.1.0 Mar 2020)

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IS66WVE2M16ECLL-70BLI IS66WVE4M16EALL-70BLI IS61WV102416DBLL-10TLI CY7C1381KV33-100AXC CY7C1460KV25
200BZI CY7C1373KV33-100AXC CY7C1381KVE33-133AXI CY7C4121KV13-600FCXC CY7C4142KV13-106FCXC GS882Z18CD-150I

GS81284Z36B-250I IS66WVC2M16ECLL-7010BLI 7140LA35PDG CY7C1380KV33-250AXC AS6C8016-55BINTR 7140LA100PDG

AS7C34096B-10TIN AS6C8016-55TIN IS62WV25616EALL-55TLI CY7C1460KV25-200BZXI CY7C1460KV25-167BZXI

CY7C1370KV25-200AXC 71421LA55JI8 CY62157G30-45ZSXI IS61VVPS102436B-200B3LI IS66WVC2M16EALL-7010BLI

IS66WVE4M16EALL-70BLI-TR R1LP0108ESN-5SI#S1 R1LV0216BSB-5SI#S1 R1LP0408DSB-5SI#S1 71V016SA12BFGI

71V016SA15YGI8 71V016SA20YGI 71V124SA15YGI8 71V65603S100BGI 71V67803S150BQ R1RP0416DGE-2PR#B0

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